

Vishay Siliconix

# N-Channel 60 V (D-S) Fast Switching MOSFET

### **DESCRIPTION**

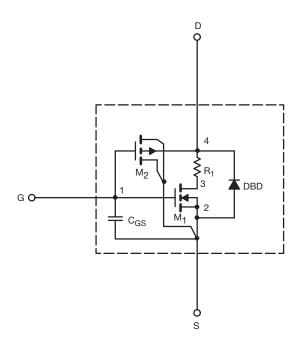
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge

### SUBCIRCUIT MODEL SCHEMATIC



## Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# **SPICE Device Model Si7850DP**

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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.95	-	V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	248	-	Α
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 10.3 \text{ A}$	0.017	0.018	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 8.7 \text{ A}$	0.023	0.025	
Forward Transconductancea	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 10.3 \text{ A}$	22	26	S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 3.8 \text{ A}, V_{GS} = 0 \text{ V}$	0.80	0.85	V
Dynamic <sup>b</sup>					
Total Gate Charge	Qg	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10.3 A	17.5	18	nC
Gate-Source Charge	Q <sub>gs</sub>		3.4	3.4	
Gate-Drain Charge	Q <sub>gd</sub>		5.3	5.3	
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DD} = 30 \text{ V}, R_L = 30 \Omega$ $I_D = 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$ $I_F = 3.8 \text{ A}, dI/dt = 100 \text{ A/}\mu\text{s}$	22	10	ns
Rise Time	t <sub>r</sub>		25	10	
Turn-Off Delay Time	t <sub>d(off)</sub>		42	25	
Fall Time	t <sub>f</sub>		48	12	
Source-Drain Reverse Recovery Time	t <sub>rr</sub>		39	50	

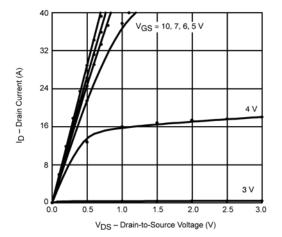
#### **Notes**

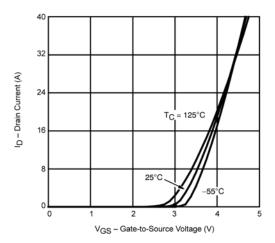
- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

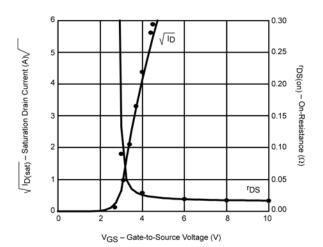
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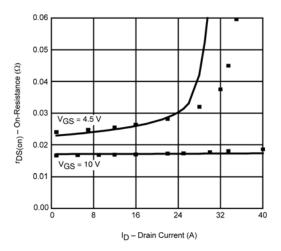
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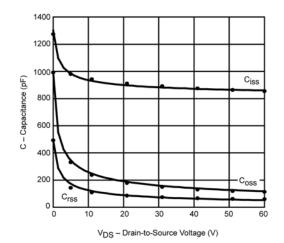
## COMPARISON OF MODEL WITH MEASURED DATA (T<sub>J</sub> = 25 °C, unless otherwise noted)

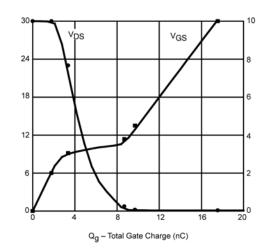












#### Note

· Dots and squares represent measured data.



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